

# 2STF2340 2STN2340

## Low voltage fast-switching PNP power transistors

### Features

- Very low collector-emitter saturation voltage
- High current gain characteristic
- Fast switching speed

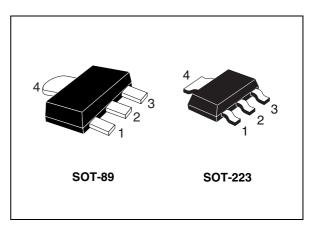
### **Applications**

- LED
- Motherboard & hard disk drive
- Mobile equipment
- DC-DC converter

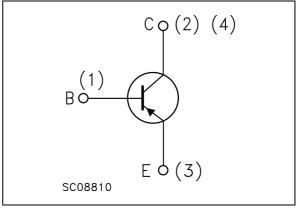
## Description

The devices are PNP transistors manufactured using new "PB-HDC" (power bipolar high density current) technology. The resulting transistor shows exceptional high gain performances coupled with very low saturation voltage.

The 2STF2340 complementary PNP is the 2STF1340.



#### Figure 1. Internal schematic diagram



#### Table 1. Device summary

Order codes	Marking	Packages	Packaging
2STF2340	2340	SOT-89	Tape and reel
2STN2340	N2340	SOT-223	Tape and reel

## 1 Electrical ratings

#### Table 2.Absolute maximum rating

		Value		
Symbol	Parameter	2STF2340	2STN2340	Unit
		SOT-89	SOT-223	
V <sub>CES</sub>	Collector-emitter voltage ( $V_{BE} = 0$ )	-4	0	V
V <sub>CEO</sub>	Collector-emitter voltage (I <sub>B</sub> = 0)	tor-emitter voltage (I <sub>B</sub> = 0) -40		V
V <sub>EBO</sub>	Emitter-base voltage ( $I_C = 0$ ) -5		V	
۱ <sub>C</sub>	Collector current -3		А	
I <sub>CM</sub>	Collector peak current (t <sub>P</sub> < 5 ms) -6		А	
P <sub>TOT</sub>	Total dissipation at $T_{amb} = 25 \text{ °C}$ 1.4 1.6		W	
T <sub>STG</sub>	Storage temperature -65 to 150		°C	
TJ	Max. operating junction temperature 150		°C	

#### Table 3.Thermal data

Symbol	Parameter	SOT-89	SOT-223	Unit
R <sub>thJA</sub> <sup>(1)</sup>	Thermal resistance junction-ambient max	89	78	°C/W

1. Device mounted on PCB area of 1  $\text{cm}^2$ 



## 2 Electrical characteristics

 $T_{case} = 25 \ ^{\circ}C$  unless otherwise specified

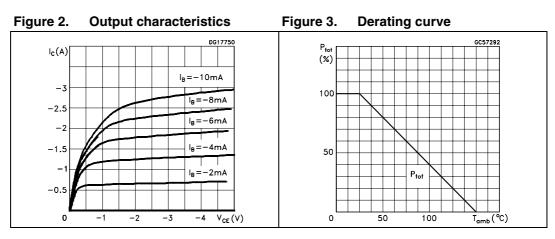
Table 4.	Electrical	characteristics
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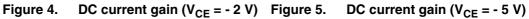
Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
Symbol	Farameter	Test conditions	IVIIII.	тур.	wax.	Unit
I <sub>CBO</sub>	Collector cut-off current $(I_E = 0)$	V <sub>CB</sub> = - 40 V			-0.1	μA
I <sub>EBO</sub>	Emitter cut-off current (I <sub>C</sub> = 0)	V <sub>EB</sub> = - 5 V			-0.1	μA
V <sub>(BR)CBO</sub> <sup>(1)</sup>	Collector-base breakdown voltage (I <sub>E</sub> = 0)	Ι <sub>C</sub> = - 100 μΑ	-40			V
V <sub>(BR)CEO</sub> <sup>(1)</sup>	Collector-emitter breakdown voltage $(I_B = 0)$	I <sub>C</sub> = - 10 mA	-40			V
V <sub>(BR)EBO</sub>	Emitter-base breakdown voltage (I <sub>C</sub> = 0)	I <sub>E</sub> = - 100 μA	-5			V
V <sub>CE(sat)</sub> <sup>(1)</sup>	Collector-emitter saturation voltage	$I_{C} = -2 A$ $I_{B} = -100 mA$ $I_{C} = -3 A$ $I_{B} = -150 mA$			-250 -350	mV mV
V <sub>BE(sat)</sub> <sup>(1)</sup>	Base-emitter saturation voltage	I <sub>C</sub> = - 2 A I <sub>B</sub> = - 100 mA			-1.2	V
h <sub>FE</sub> <sup>(1)</sup>	DC current gain		100 180	220	450	
f <sub>t</sub>	Transition frequency	I <sub>C</sub> = - 0.1 A V <sub>CE</sub> = - 5 V f = 100 MHz	100			MHz
C <sub>CBO</sub>	Collector-base capacitance (I <sub>E</sub> = 0)	V <sub>CB</sub> = - 10 V f = 1 MHz		50		pF
t <sub>on</sub> t <sub>off</sub>	Resistive load Turn-on time Turn-off time	$      I_{C} = -1.5 \text{ A}  V_{CC} = -10 \text{ V} \\       I_{B(on)} = -I_{B(off)} = -150 \text{ mA} \\       V_{BB(off)} = 5 \text{ V} $		80 450		ns ns

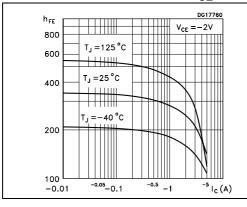
1. Pulse test: pulse duration  $\leq$  300  $\mu s,$  duty cycle  $\leq$  2 %

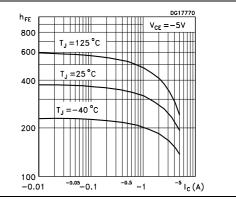


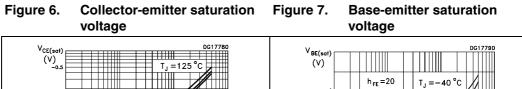
### 2.1 Electrical characteristics (curves)

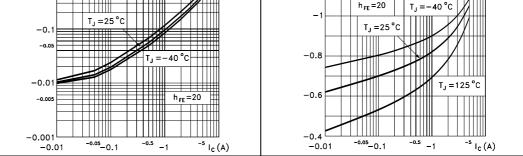


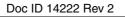


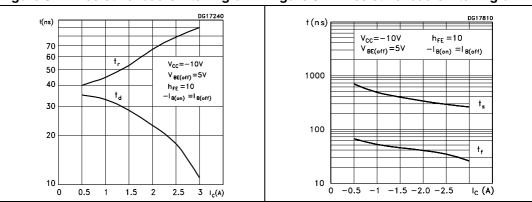






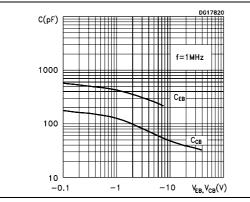




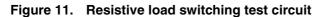


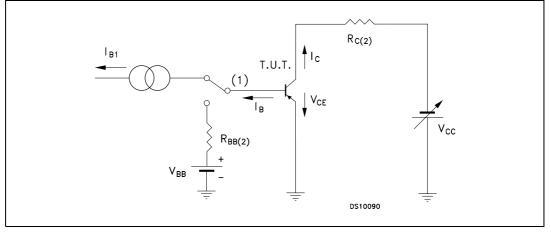
### Figure 8. Resistive load switching on Figure 9. Resistive load switching off





### 2.2 Test circuits





- 1. Fast electronic switch
- 2. Non-inductive resistor



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## 3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: *www.st.com*. ECOPACK<sup>®</sup> is an ST trademark.

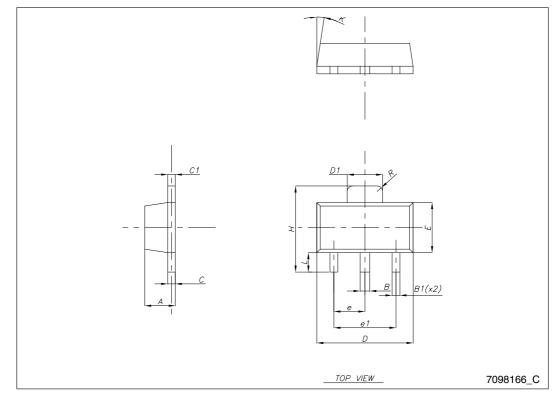


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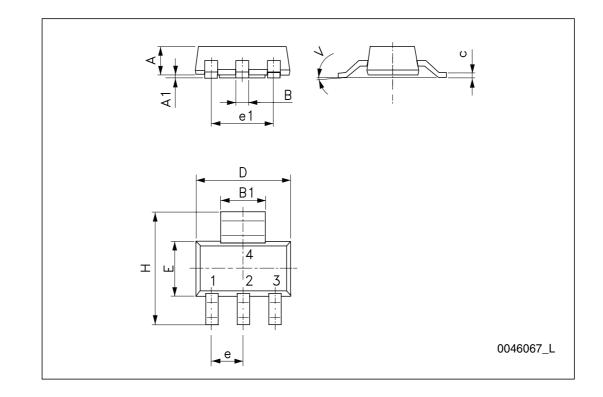
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SOT-89 mechanical data			
		mm	
Dim.	Min.	Тур.	Max.
А	1.40		1.60
В	0.44		0.56
B1	0.36		0.48
С	0.35		0.44
C1	0.35		0.44
D	4.40		4.60
D1	1.62		1.83
E	2.29		2.60
е	1.42		1.57
e1	2.92		3.07
Н	3.94		4.25
К	1°		8°
L	0.89		1.20
R		0.25	



	SOT-223 mechanical data					
DIM.		mm.				
DIW.	min.	typ	max.			
А			1.80			
A1	0.02		0.1			
В	0.60	0.70	0.85			
B1	2.90	3.00	3.15			
С	0.24	0.26	0.35			
D	6.30	6.50	6.70			
е		2.30				
e1		4.60				
E	3.30	3.50	3.70			
Н	6.70	7.00	7.30			
V			10 °			





## 4 Revision history

#### Table 5.Document revision history

Date	Revision	Changes	
04-Dec-2007	1	Initial release.	
19-Oct-2009	2	Inserted 2STN2340 in SOT-223 package.	



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